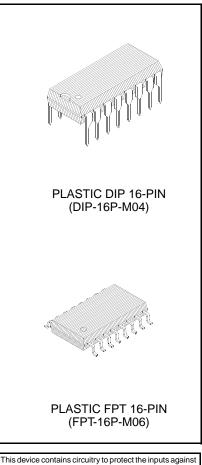
ASSP SWITCHING REGULATOR CONTROLLER

MB3769A

The Fujitsu MB3769A is a pulse-width-modulation controller which is applied to fixed frequency pulse modulation technique. The MB3769A contains wide band width Op-Amp and high speed comparator to construct very high speed switching regulator system up to 700 kHz. Output is suitable for power MOS FET drive owing to adoption of totem pole output.

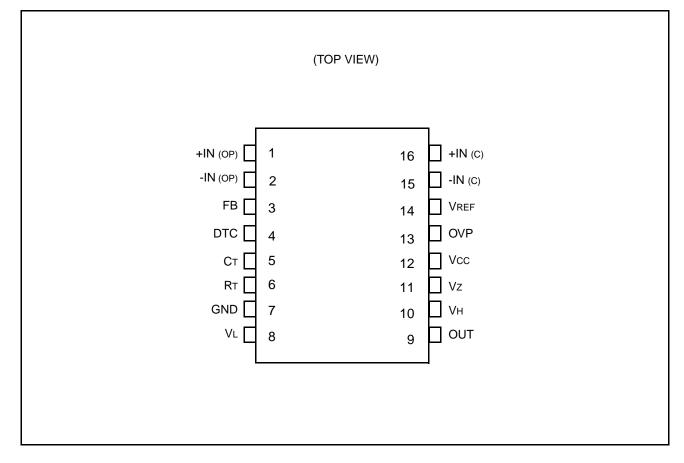
The MB3769A provides stand-by mode at low voltage power supply when it is applied in primary control system.

- High frequency oscillator (f = 1 to 700 kHz)
- On-chip wide band frequency operation amplifier (BW = 8 MHz typ.)
- On-chip high speed comparator (td = 120 ns typ.)
- Internal reference voltage generator provides a stable reference supply (5 V \pm 2%)
- Low power dissipation (1.5 mA typ. at standby mode, 8 mA typ. at operating mode)
- Output current \pm 100 mA (\pm 600 mA at peak)
- High speed switching operation (tr = 60 ns, tf = 30 ns, CL = 1000 pF typ.)
- Adjustable Dead-time
- On-chip soft start and quick shut down functions
- Internal circuitry prohibits double pulse at dynamic current limit operation
- Under voltage lock out function (OFF to ON: 10 V typ. ON to OFF: 8 V typ.)
- On-chip output shut down circuit with latch function at over voltage
- On-chip Zener diode (15 V)



This device contains circuitry to protect the inputs against damage due to high static voltages or electric fields. However, it is advised that normal precautions be taken to avoid application of any voltage higher than maximum rated voltages to this high impedance circuit.

■ PIN ASSIGNMENT



■ ABSOLUTE MAXIMUM RATINGS (See NOTE)

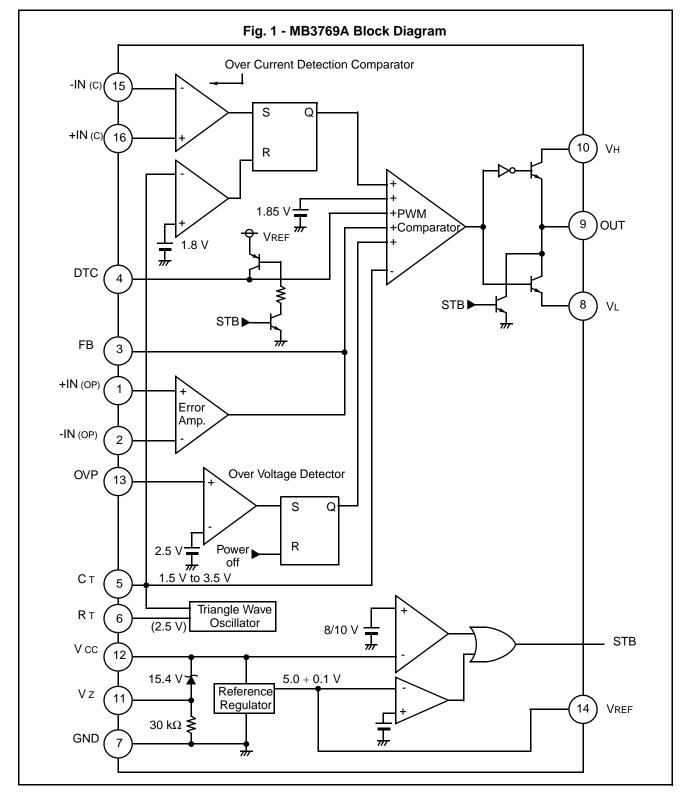
Rating	Symbol	Value	Unit
Power Supply Voltage	Vcc	20	V
Output Current	Ιουτ	120 (660*)	mA
Operation Amp. Input Voltage	Vin (OP)	Vcc + 0.3 (≤ 20)	V
Power Dissipation: DIP	PD	1000**	mW
: FPT	PD	620***	mW
Operating Temp. : DIP	Тор	-30 to +85	Ο°
: FPT	Тор	-30 to +75	Ο°
Storage Temp.	TSTG	-55 to +125	٥C

* : Duty ≤ 5%

** : TA = 25 °C

- *** : TA = 25 °C, FPT package is mounted on the epoxy board. (4 cm x 4 cm x 0.15 cm)
- **NOTE :** Permanent device damage may occur if the above **Absolute Maximum Ratings** are exceeded. Functional operation should be restricted to the conditions as detailed in the operational sections data sheet. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

BLOCK DIAGRAM



RECOMMENDED OPERATING CONDITION

Parameter	SymboL	DIP package			FPT package			11
Parameter		Min	Тур	Max	Min	Тур	Max	Unit
Power Supply Voltage	Vcc	12	15	18	12	15	18	V
Output Current (DC)	Ιουτ	-100	-	100	-100	-	100	mA
Output Current (Peak)	IOUT PEAK	-600	-	600	-600	-	600	mA
Operation Amp. Input voltage	VINOP	-0.2	0 to VREF	Vcc -3	-0.2	0 to VREF	Vcc-3	V
FB Sink Current	Isink	-	-	0.3	-	-	0.3	mA
FB Source Current	ISOURCE	-	-	2	-	-	2	mA
	VINC ⁺	-0.3	0 to 3	Vcc	-0.3	0 to 3	Vcc	V
Comparator Input Voltage	VINC	-0.3	0 to 2	2.5	-0.3	0 to 2	2.5	V
Reference Section Output Current	IREF	-	5	10	-	2	10	mA
Timing Resistor	RT	9	18	50	9	18	50	kΩ
Timing Capacitor	Ст	100	680	10 ⁶	100	680	10 ⁶	pF
Oscillator Frequency	fosc	1	100	700	1	100	700	kHz
Zener Current	Iz	-	-	5	-	-	5	mA
Operating Temp.	Тор	-30	25	85	-30	25	75	°C

■ ELECTRICAL CHARACTERISTICS

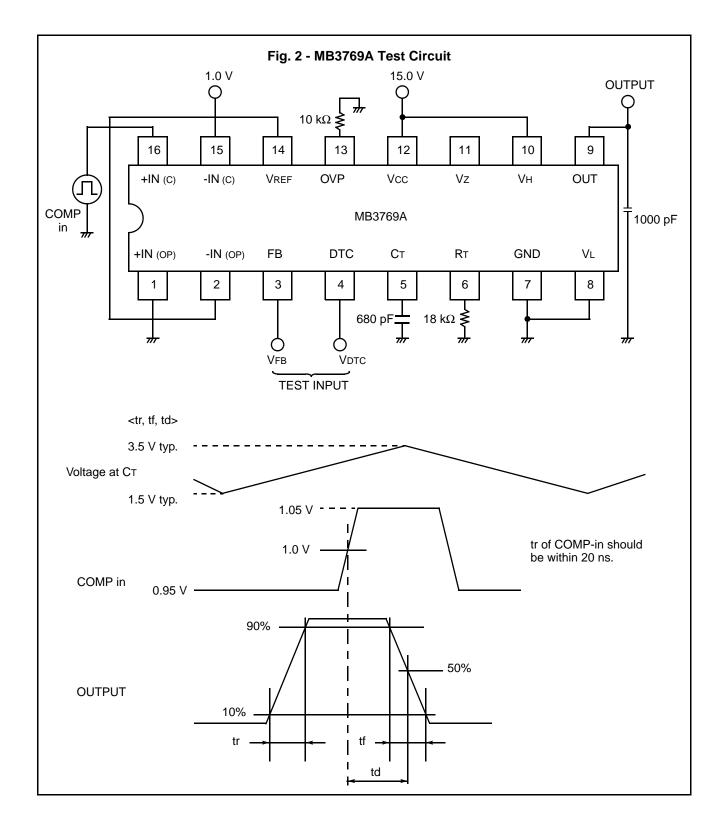
					4=25°C)			
	Parameter		Symbol Conditior	Condition	Value			Unit
		Cymbol		Min	Тур	Мах		
Reference Section	Output Voltage		Vref	IREF = 1 mA	4.9	5.0	5.1	V
	Input Regulation		Δ VRIN	$12 \text{ V} \leq \text{Vcc} \leq 18 \text{ V}$	-	2	15	mV
	Load Regulation	Load Regulation		$1 \text{ mA} \leq \text{Iref} \leq 10 \text{ mA}$	-	-1	-15	mV
	Temp. Stability		$\Delta VRTEMP$	$-30~^\circ C \le T A \le 85~^\circ C$	-	±200	±750	μV/ °C
	Short Circuit O	utput Current	Isc	Vref = 0 V	15	40	-	mA
Ossillatar	Oscillator Frequency		fosc	RT=18 kΩ CT=680 pF	90	100	110	kHz
Oscillator Section	Voltage Stability		Δ foscin	$12 \text{ V} \leq \text{Vcc} \leq 18 \text{ V}$	-	±0.03	-	%
	Temp. Stability		Δ fosc / Δ T	$-30 \ ^{\circ}C \le TA \le 85 \ ^{\circ}C$	-	±2	-	%
Dead -time Control Section	Input Bias Current		ID		-	2	10	μA
	Max. Duty Cycle		Dmax	Vd = 1.5 V	75	80	85	%
	Duty Cycle Set		Dset	Vd = 0.5 VREF	45	50	55	%
	Input Threshold Voltage	0% Duty Cycle	Vdo	-	-	3.5	3.8	V
		Max. Duty Cycle	Vdm	-	1.55	1.85	-	V
	Discharge Voltage		Vdh	Vcc= 7 V, Idtc= -0.3 mA	4.5	-	-	V
	Input Offset Voltage		VIO (OP)	V3 = 2.5 V	-	±2	±10	mV
Error Amplifier Section	Input Offset Current		IIO (OP)	V3 = 2.5 V	-	±30	±300	nA
	Input Bias Current		lir (OP)	V3 = 2.5 V	-1	-0.3	-	μA
	Common-Mode Input Voltage		VCM (OP)	$12 \text{ V} \leq \text{Vcc} \leq 18 \text{ V}$	-0.2	-	Vcc -3	V
	Voltage Gain		AV (OP)	$0.5~V \leq V_3 \leq 4~V$	70	90	-	dB
	Band Width		BW	Av = 0dB	-	8	-	MHz
	Slew Rate		SR	$RL = 10 \text{ k}\Omega$, $AV = 0 \text{dB}$	-	6	-	V/µs
	Common-Mode Rejection Rate		CMR	VIN = 0 to 10 V	65	80	-	dB
	"H" Level Output Voltage		Voн	l3 = -2 mA	4.0	4.6	-	V
	"L" Level Output Voltage		Vol	l3 = 0.3 mA	-	0.1	0.5	V

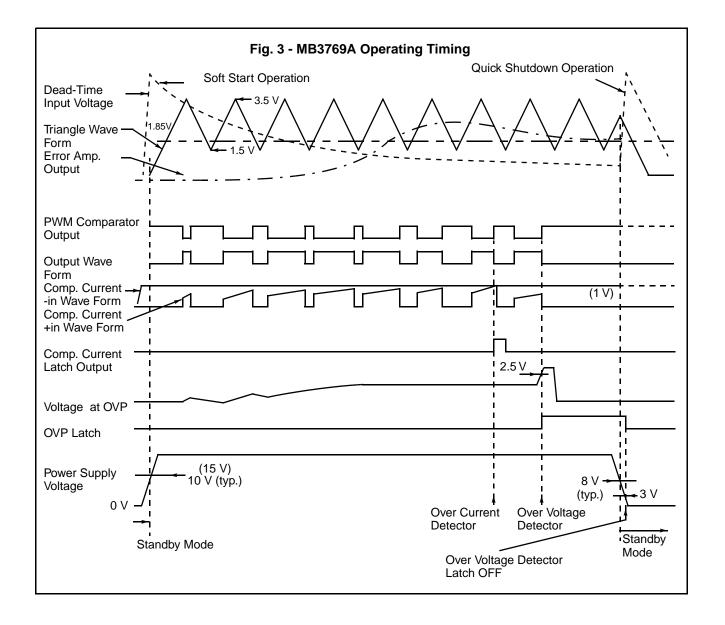
ELECTRICAL CHARACTERISTICS (Continued)

(Vcc=15V, TA=25°C)

	Parameter	Symbol	Condition		Unit		
raiailletei		Symbol	Condition	Min	Тур	Max	Unit
Current Comparator	Input Offset Voltage	VIO (C)	VIN = 1 V	-	±5	±15	mV
	Input Bias Current	IIB (C)	VIN = 1 V	-5	-1	-	μA
	Common-Mode Input Volt- age			0	-	2.5	V
	Voltage Gain	AV (C)	-	-	200	-	V/V
	Response Time	td	50 mV over drive	-	120	250	ns
PWM Comporter	0% Duty Cycle	Vopo	Rτ = 18 kΩ	-	3.5	3.8	V
Comparator Section	Max. Duty Cycle	Vopm	C⊤ = 680 pF	1.55	1.85	-	V
Output Section	"H" Level Output Voltage	Vн	IOUT = -100 mA	12.5	13.5	-	V
	"L" Level Output Voltage	VL	IOUT = 100 mA	-	1.1	1.3	V
	Rise Time	tr	C∟ = 1000 pF, RL = ∞	-	60	120	ns
	Fall Time	tf	C∟ = 1000 pF, RL = ∞	-	30	80	ns
Over	Threshold Voltage	Vovp	-	2.4	2.5	2.6	V
Voltage Detector	Input Current	IIOVP	VIN = 0 V	-1.0	-0.2	-	μΑ
Delector	Vcc Reset	VCC RST	-	2.0	3.0	4.5	V
Under Volt- age Out Stop	Off to On	Vтнн	-	9.2	10.0	10.8	V
	On to Off	VTHL	-	7.2	8.0	8.8	V
Supply Current	Standby *	ISTB	RT = 18 kΩ 4 pin Open	-	1.5	2.0	mA
	Operating	Icc	R⊤ = 18 kW	-	8.0	12.0	mA
	Zener Voltage	Vz	lz = 1 mA	-	15.4	-	V
	Zener Current	Iz	V ₁₁₋₇ = 1 V	-	0.03	-	mA

* : VCC = 8V



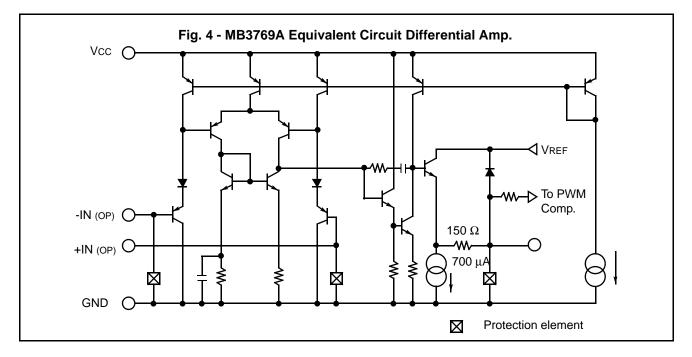


■ FUNCTIONS

1. Error Amplifier

The error amplifier detects the output voltage of the switching regulator.

The error amplifier uses a high-speed operational amplifier with an 8 MHz bandwidth (typical) and 6 V/ms slew rate (typical). For ease of use, the common mode input voltage ranges from -0.2 V to Vcc-3 V. Figure 4 shows the equivalent circuit.



2. Overcurrent Detection Comparator

There are two methods for protection of the output transistor of this device from overcurrents; one restricts the transistor's ontime if an overcurrent that flows through the output transistor is detected from an average output current, and the other detects an overcurrent in the external transistor (FET) and shuts the output down instantaneously. Using average output currents, the peak current of the external transistor (FET) cannot be detected, so an output transistor with a large safe operation area (SOA) margin is required.

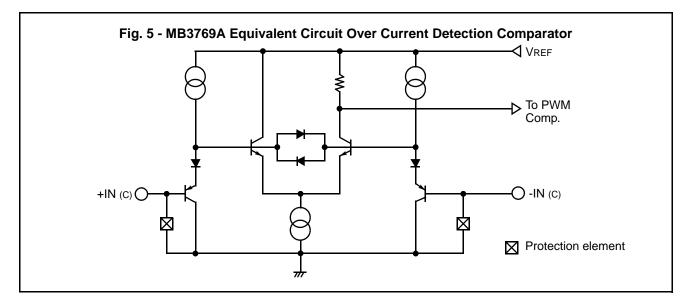
For the method of detecting overcurrents in the external transistor (FET), the output transistor can be protected against a shorted filter capacitor or power-on surge current.

The MB3769A uses dynamic current limiting to detect overcurrents in the output transistor (FET). A high-speed comparator and flip-flop are built-in.

To detect overcurrents, compare the voltage at +IN(c) of current detection resistor connected the source of the output transistor (FET), with the reference voltage (connected to -IN(c)) using a comparator. To prevent output oscillation during overcurrent, flip-flop circuit protects against double pulses occurring within a cycle.

The output of overcurrent detector is ORed with other signals at the PWM comparator. See the example Application Example for details on use.

Figure 5 shows the equivalent circuit of the over-current detection comparator.



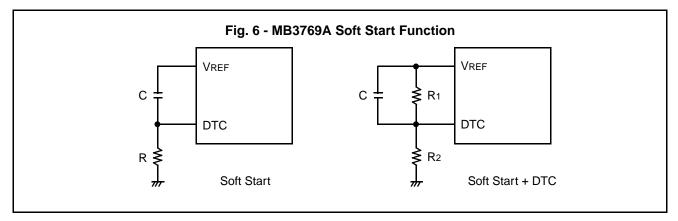
3. DTC: Dead Time Control (Soft-Start and Quick Shutdown)

The dead time control terminal and the error amplifier output are connected to the PWM comparator. The maximum duty cycle for VDTC (voltage applied to pin 4) is obtained from the following formula (approximate value at low frequency):

Duty Cycle = $(3.5 - VDTC) \times 50$ (%) $[0\% \le duty cycle \le DMAX (80\%)]$

The dead time control terminal is used to provide soft start.

In Figure 6, the DTC terminal is connected to the VREF terminal through R and C. Because capacitor C does not charge instantaneously when the power is turned on, the output transistor is kept turned off. The DTC input voltage and the output pulse width increase gradually according to the RC time constant so that the control system operates safely.



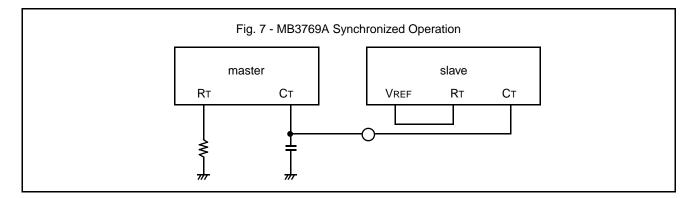
The quick shutdown function prevents soft start malfunction when the power is turned off and on quickly. After the power is shut down, soft start is disabled because the DTC terminal has low electric potential from the beginning if the power is turned on again before the capacitor is discharged. The MB3769A prevents this by turning on the discharge transistor to quickly discharge the capacitor in the stand-by mode.

4. Triangular Wave Oscillator

The oscillation frequency is expressed by the following formula:

$$fosc \simeq \frac{1}{0.8 \times CT \times RT + 0.0002 \text{ ms}} \begin{bmatrix} kHz \end{bmatrix} \begin{bmatrix} CT & :\mu F \\ RT & :k\Omega \end{bmatrix}$$

For master/slave synchronized operation of several MB3769As, the CT and RT terminals of the master MB3769A are connected in the usual way and the CT terminals of the master and slave device (s) are connected together. The slave MB3769A's RT terminal is connected to it's VREF terminal to disable the slave's oscillator. In this case, set 50/n k Ω (n is the number of master and slave ICs) to the upper limit of RT so that internal bias currents do not stop the master oscillation.



5. Overvoltage Detector

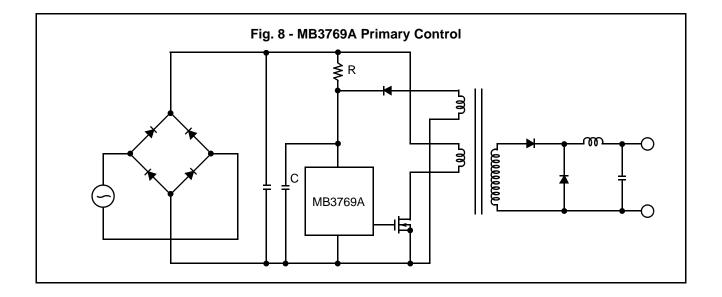
The overvoltage detection circuit shuts the system power down if the switching regulator's output voltage is abnormal or if abnormal voltage is appeared. The reference voltage is 2.5 V (VREF /2). The system power is shut down if the voltage at pin 13 rises above 2.5 V. The output is kept shut down by the latching circuit until the power supply is turned off (see Figure 3).

6. Stand-by Mode and Under-Voltage Lockout (UVLO)

Generally, VGs > 6 to 8 V is required to use power MOSFET for switching. UVLO is set so that output is on at Vcc \ge 10 V (standard) when the power is turned on and is off at Vcc \le 8 V (standard) when the power is turned off.

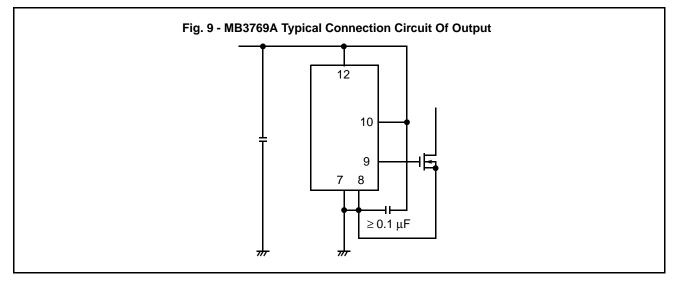
In the stand-by mode, the power supply current is limited to 2 mA or less when the output is inhibited by the UVLO circuit. When the MB3769A is operated from the 100 VAC line, the power supply current is supplied through resistor R (Figure 8). That is, the IC power supply current is supplied by the AC line through resistor R until operation starts. Current is then supplied from the transformer tertiary winding, eliminating the need for a second power supply.

Two volts (typical) of hysteresis are provided for return from operation mode to stand-by mode not to return to stand-by mode until output power is turned on or to avoid malfunction due to noise.

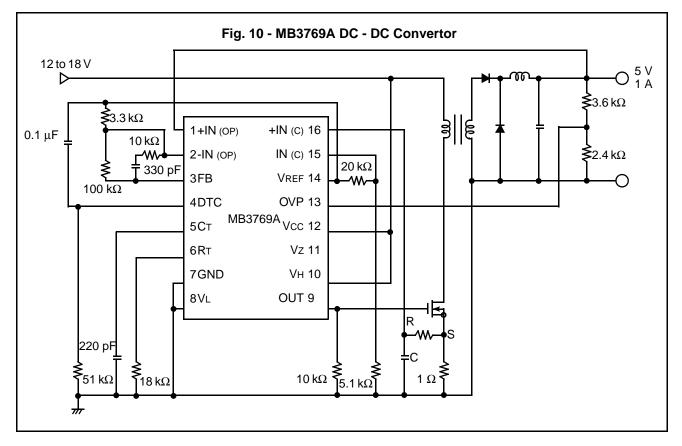


7. Output Section

Because the output terminal (pin 9) carries a large current, the collector and emitter of the output transistor are brought out to the VH and VL terminals. In principle, VH is connected to VCC and VL is connected to GND, but VH can be supplied from another power supply (4 to 18 V). Note that VL and GND should be connected as close to the IC package as possible. A capacitor of 0.1 μ F or more is inserted between VH and VL (see Figure 9).

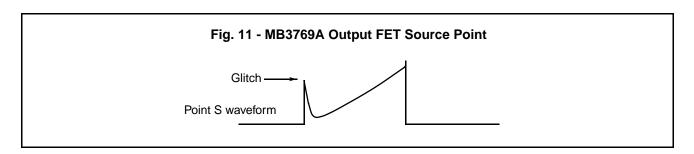


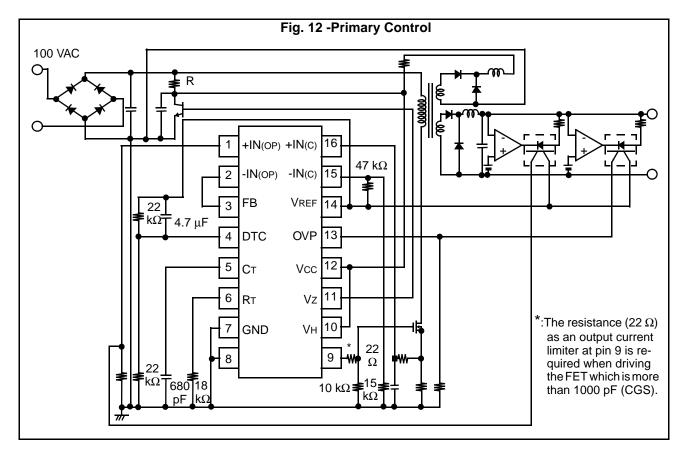
■ APPLICATION EXAMPLE

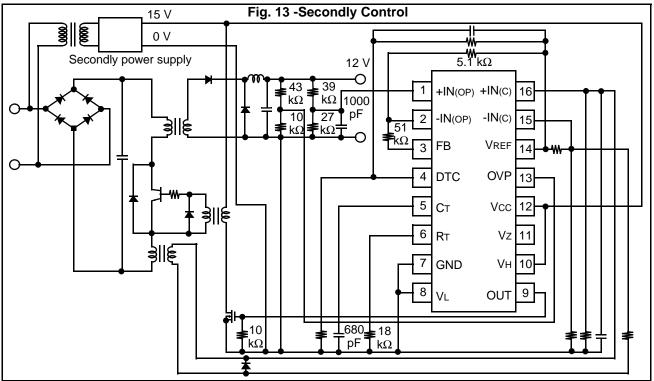


Overcurrent Protection Circuit

The waveform at the output FET source terminal is shown in Figure 11. The RC time constant must be chosen so that the voltage glitch in the waveform does not cause erroneous overcurrent detection. This time constant is should be from 5 to 100 ns. A detection current value depends on R or C because a waveform is weakened. To keep this glitch as small as possible, the rectifiers on the transformer secondary winding must be the fast-recovery type.

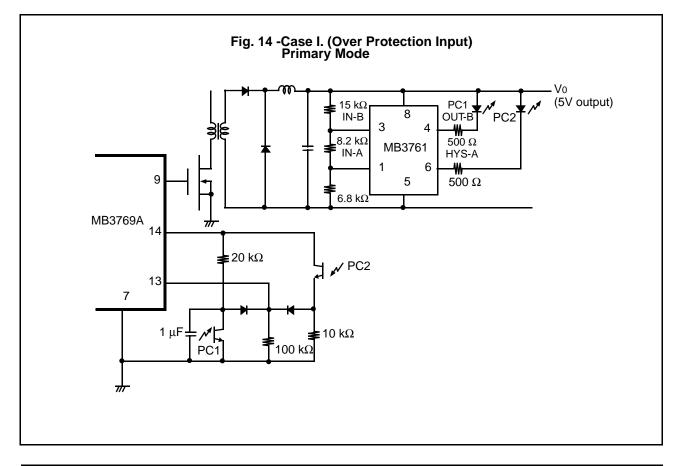


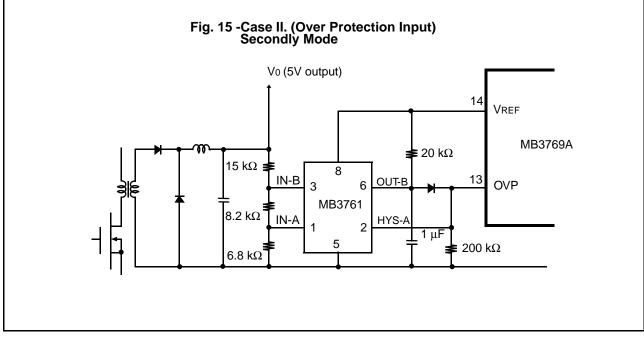




SHORT PROTECTION CIRCUIT

The system power can be shut down to protect the output against intermittent short-circuits or continuous overloads. This protection circuit can be configured using the OVP input as shown in Figure 14.

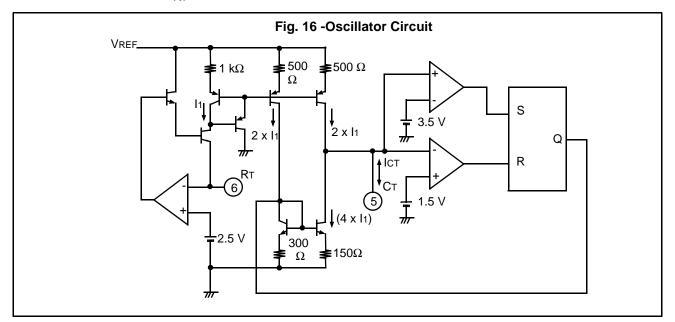




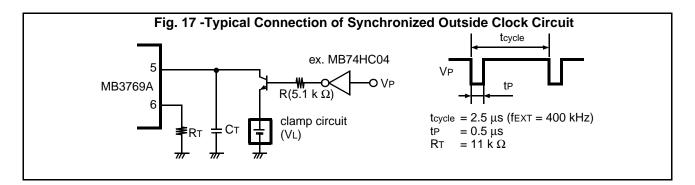
■ HOW TO SYNCHRONIZE WITH OUTSIDE CLOCK

The MB3769A oscillator circuit is shown in Figure 16. CT charge and discharge currents are expressed by the following formula:

 $ICT = \pm 2 x I_1 = \pm \frac{5 V}{RT}$



This circuit shows that if the voltage at the CT terminal is set to 1.5 V or less, one oscillation cycle ends and the next cycle starts. An example of an external synchronous clock circuit is shown in Figure 17.

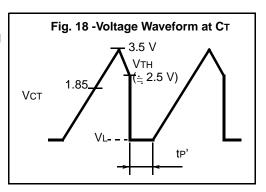


The Figure 18 shows the CT terminal waveform. VTH may be near 2.5 V. In this case, the maximum duty cycle is restricted as shown in the formula below if tP' = 0.

$$D_{max} = \frac{(3.5 - 1.85) + (3.5 - V_{TH})}{(3.5 - V_L) + (3.5 - V_{TH})} \le 59\% \text{ (VL} = 0 \text{ V: No clamp circuit)}$$

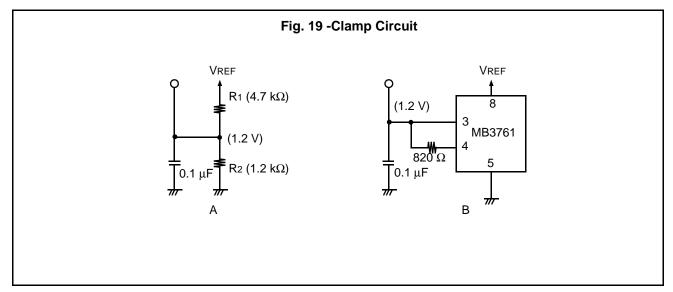
When VTH = 2.5 V, CT can be provided by followings.

tcycle - tP =
$$\frac{1}{\text{fosc}} \times \frac{(3.5 - \text{VL}) + (3.5 - \text{VTH})}{\text{fosc}(3.5 - 1.5) \times 2}$$



$$\begin{array}{rcl} \text{fosc} \simeq & \frac{1}{0.8 \text{ x CT x RT}} \\ \text{CT} \simeq & \frac{1}{0.8 \text{ x RT}} & \text{x} & \frac{4}{4.5 \text{ - VL}} & (\text{tcycle - tP}) \text{ [pF] (RT: } \text{ k}\Omega, \text{ tcycle, tP: ns)} \end{array}$$

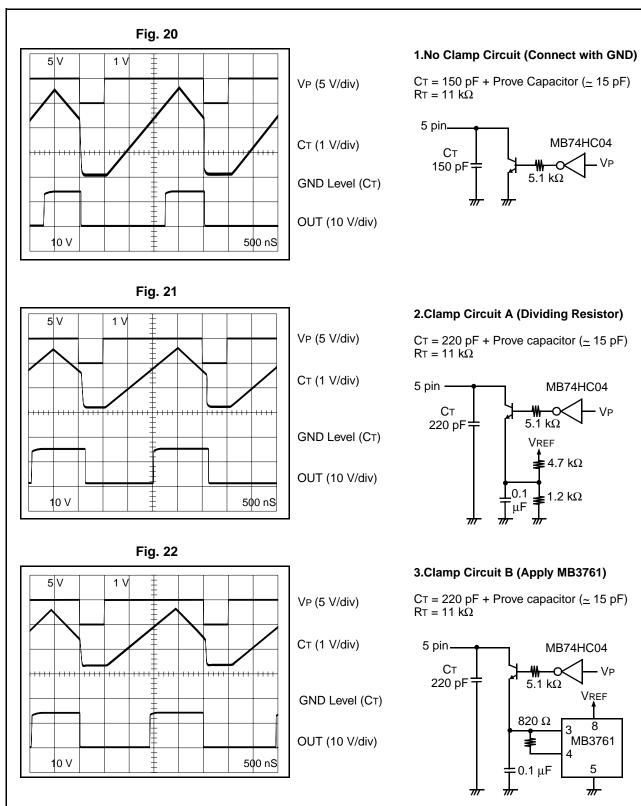
Make VL high for a large duty cycle for the clamp circuit. The circuits below can be used because the clamp voltage must be much lower than 1.5 V.

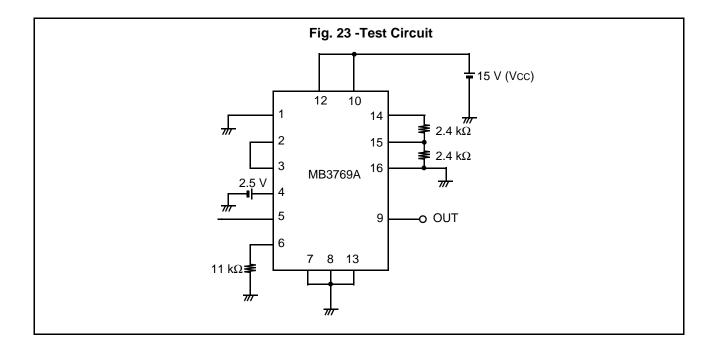


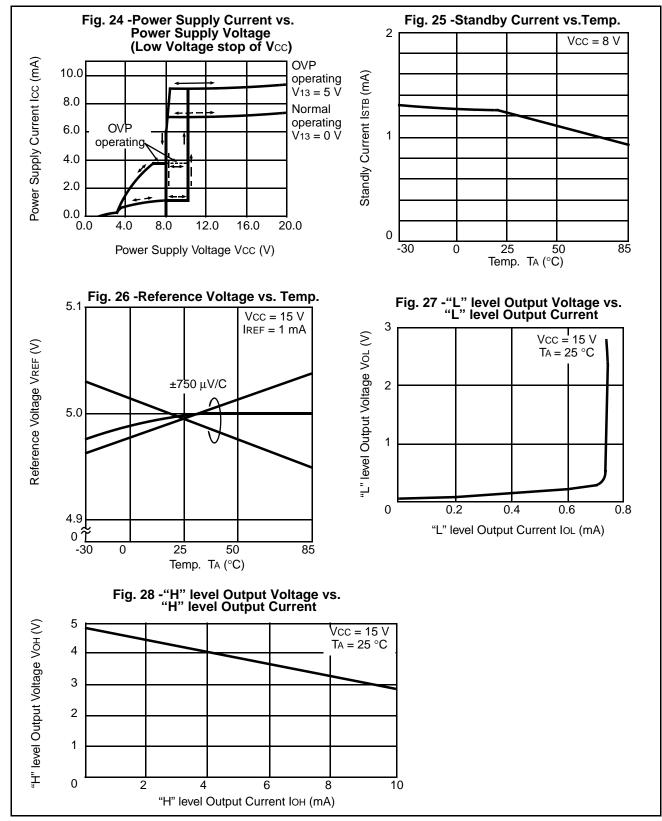
In circuit A, R1 and R2 must be determined considering the effects of tP, R, or RT.

The transistor saturation voltage must be very small (<0.15 V) for any clamp circuit, so a transistor with a very small VCE (sat) should be used.

SYNCHRONIZED OUTSIDE CLOCK CIRCUIT

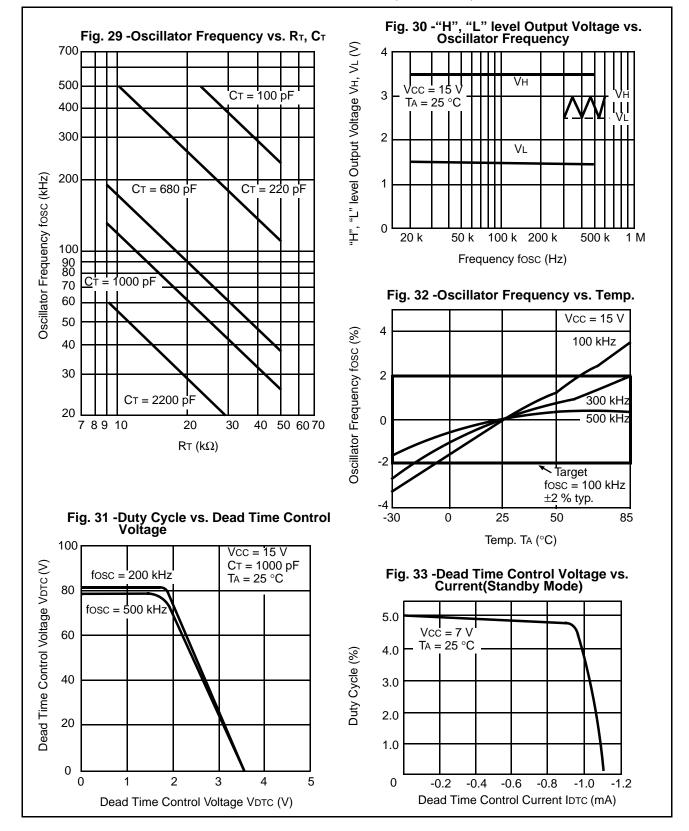


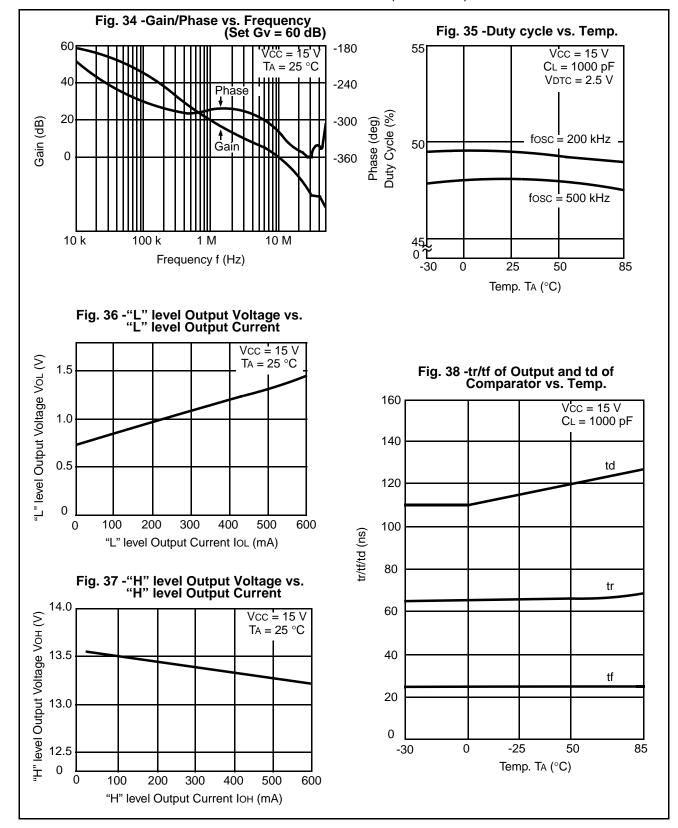




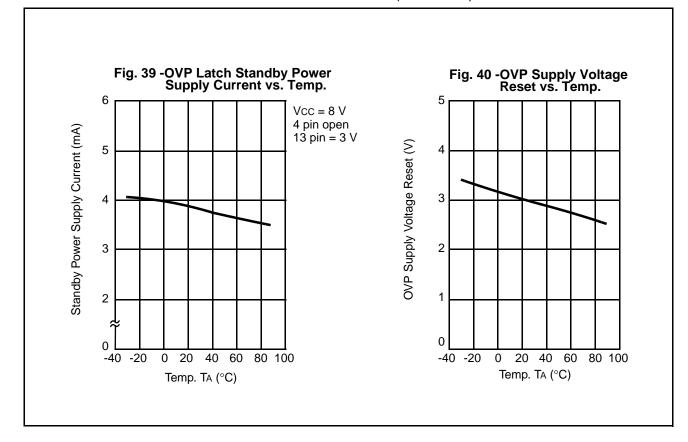
TYPICAL PERFORMANCE CHARACTERISTICS

TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

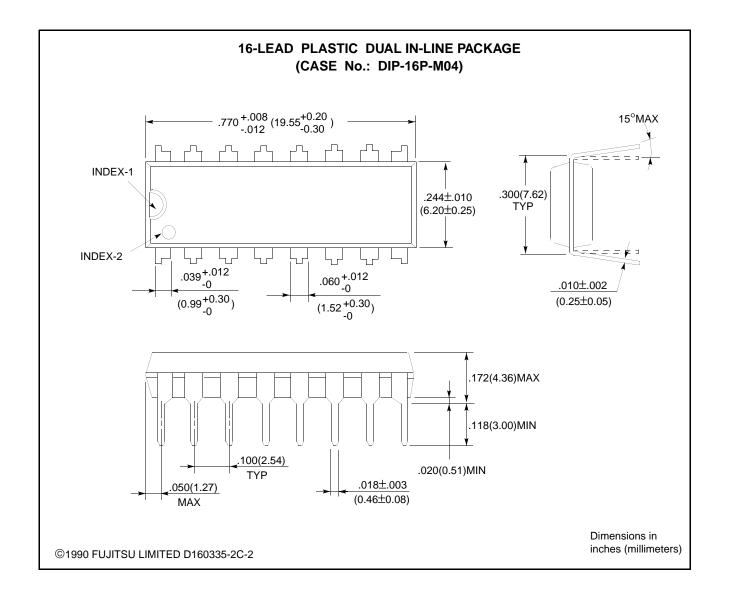




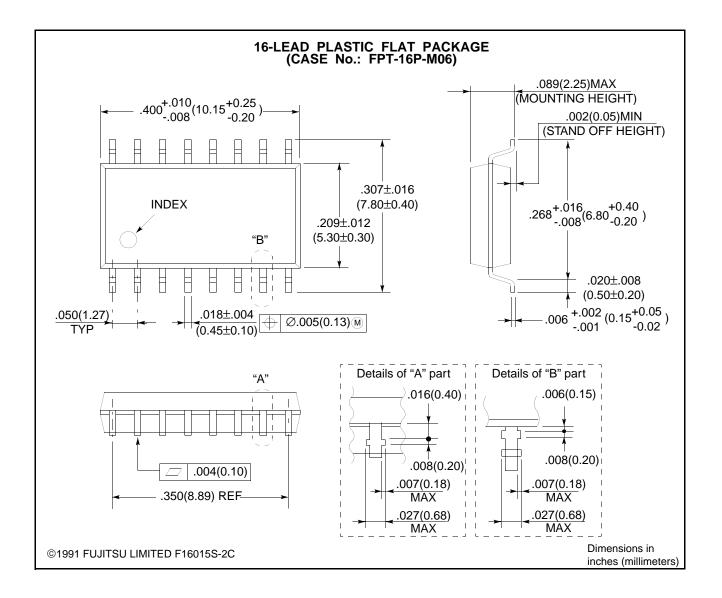
TYPICAL PERFORMANCE CHARACTERISTICS (Continued)



■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)



24



FUJITSU LIMITED

All Rights Reserved.

The contents of this document are subject to change without notice. Customers are advised to consult with FUJITSU sales representatives before ordering.

The information and circuit diagrams in this document are presented as examples of semiconductor device applications, and are not intended to be incorporated in devices for actual use. Also, FUJITSU is unable to assume responsibility for infringement of any patent rights or other rights of third parties arising from the use of this information or circuit diagrams.

The products described in this document are designed, developed and manufactured as contemplated for general use, including without limitation, ordinary industrial use, general office use, personal use, and household use, but are not designed, developed and manufactured as contemplated (1) for use accompanying fatal risks or dangers that, unless extremely high safety is secured, could have a serious effect to the public, and could lead directly to death, personal injury, severe physical damage or other loss (i.e., nuclear reaction control in nuclear facility, aircraft flight control, air traffic control, mass transport control, medical life support system, missile launch control in weapon system), or (2) for use requiring extremely high reliability (i.e., submersible repeater and artificial satellite).

Please note that Fujitsu will not be liable against you and/or any third party for any claims or damages arising in connection with above-mentioned uses of the products.

Any semiconductor devices have an inherent chance of failure. You must protect against injury, damage or loss from such failures by incorporating safety design measures into your facility and equipment such as redundancy, fire protection, and prevention of over-current levels and other abnormal operating conditions.

If any products described in this document represent goods or technologies subject to certain restrictions on export under the Foreign Exchange and Foreign Trade Law of Japan, the prior authorization by Japanese government will be required for export of those products from Japan.

F9601 © FUJITSU LIMITED Printed in Japan